

Single high-speed switching diode Rev. 1 — 12 October 2010

Product data sheet

1. **Product profile**

1.1 General description

Single high-speed switching diode, encapsulated in a SOD882D leadless ultra small Surface-Mounted Device (SMD) plastic package with visible and solderable side pads.

1.2 Features and benefits

- High switching speed: $t_{rr} \le 4$ ns
- Low leakage current
- Repetitive peak reverse voltage: $V_{RRM} \le 100 \text{ V}$
- AEC-Q101 qualified

- Low capacitance
- Reverse voltage: V_R ≤ 100 V
- Ultra small and leadless SMD plastic package
- Solderable side pads

1.3 Applications

- High-speed switching
- General-purpose switching

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I_{F}	forward current		<u>[1]</u> -	-	215	mA
I _R	reverse current	$V_R = 80 V$	-	-	0.5	μΑ
V_R	reverse voltage		-	-	100	V
t _{rr}	reverse recovery time		[2] -	-	4	ns

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB) with 60 μ m copper strip line.



^[2] When switched from I_F = 10 mA to I_R = 10 mA; R_L = 100 Ω ; measured at I_R = 1 mA.



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2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	cathode	<u>[1]</u>	
2	anode	1 2	1 2 006aab040
		Transparent top view	

^[1] The marking bar indicates the cathode.

3. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
BAS16LD	-	leadless ultra small plastic package; 2 terminals; body $1.0 \times 0.6 \times 0.4$ mm	SOD882D		

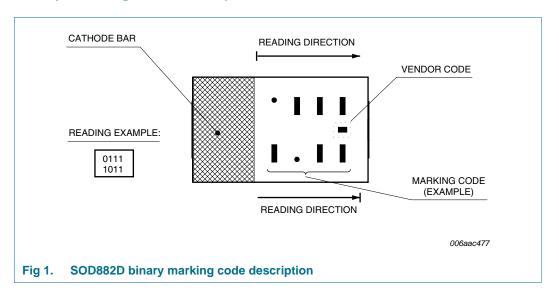
4. Marking

Table 4. Marking codes

Type number	Marking code ^[1]
BAS16LD	1000
	0000

^[1] For SOD882D binary marking code description, see Figure 1.

4.1 Binary marking code description



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5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Parameter	Conditions	Min	Max	Unit
repetitive peak reverse voltage		-	100	V
reverse voltage		-	100	V
forward current		<u>[1]</u>	215	mA
repetitive peak forward current	$t_p \leq 0.5~\mu\text{s}; \\ \delta \leq 0.25$	-	500	mA
non-repetitive peak forward current	square wave	<u>[2]</u>		
	t _p = 1 μs	-	4	А
	$t_p = 1 \text{ ms}$	-	1	А
	t _p = 1 s	-	0.5	Α
total power dissipation	$T_{amb} \le 25 ^{\circ}C$	[1][3]	250	mW
junction temperature		-	150	°C
ambient temperature		-55	+150	°C
storage temperature		-65	+150	°C
	repetitive peak reverse voltage reverse voltage forward current repetitive peak forward current non-repetitive peak forward current total power dissipation junction temperature ambient temperature	repetitive peak reverse voltage reverse voltage forward current $ \begin{array}{lll} & t_p \leq 0.5 \; \mu s; \\ \delta \leq 0.25 & \delta \leq 0.25 \\ & \text{non-repetitive peak forward current} & t_p = 1 \; \mu s \\ & t_p = 1 \; ms \\ & t_p = 1 \; s \\ & \text{total power dissipation} & T_{amb} \leq 25 \; ^{\circ}\text{C} \\ & \text{junction temperature} \\ & \text{ambient temperature} \\ \end{array} $	repetitive peak reverse voltage $ \begin{array}{ccccccccccccccccccccccccccccccccccc$	$\begin{tabular}{lllllllllllllllllllllllllllllllllll$

^[1] Device mounted on an FR4 PCB with 60 μm copper strip line.

6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1][2] -	-	500	K/W

^[1] Device mounted on an FR4 PCB with 60 μm copper strip line.

^[2] $T_i = 25$ °C prior to surge.

^[3] Reflow soldering is the only recommended soldering method.

^[2] Reflow soldering is the only recommended soldering method.

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7. Characteristics

Table 7. Characteristics

 $T_{amb} = 25$ °C unless otherwise specified.

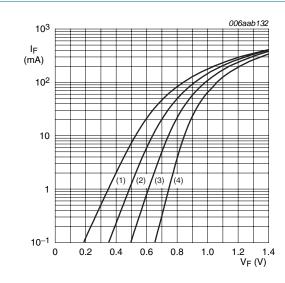
· allib = 0	C amount of community					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{F}	forward voltage		<u>[1]</u>			
		$I_F = 1 \text{ mA}$	-	-	715	mV
		$I_F = 10 \text{ mA}$	-	-	855	mV
		$I_F = 50 \text{ mA}$	-	-	1	V
		$I_F = 150 \text{ mA}$	-	-	1.25	V
I _R reverse current	reverse current	V _R = 25 V	-	-	30	nA
		$V_{R} = 80 \text{ V}$	-	-	0.5	μΑ
	$V_R = 25 \text{ V}; T_j = 150 ^{\circ}\text{C}$	-	-	30	μΑ	
		$V_R = 80 \text{ V}; T_j = 150 ^{\circ}\text{C}$	-	-	50	μΑ
C_d	diode capacitance	$f = 1 MHz; V_R = 0 V$	-	-	1.5	pF
t _{rr}	reverse recovery time		[2] _	-	4	ns
V_{FR}	forward recovery voltage		[3]	-	1.75	V

^[1] Pulse test: $t_D \le 300 \ \mu s; \ \delta \le 0.02$.

^[2] When switched from I_F = 10 mA to I_R = 10 mA; R_L = 100 Ω ; measured at I_R = 1 mA.

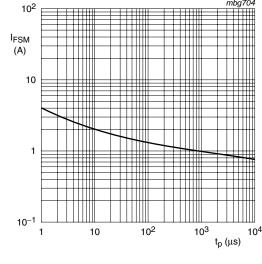
^[3] When switched from $I_F = 10$ mA; $t_r = 20$ ns.

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- (1) $T_{amb} = 150 \, ^{\circ}C$
- (2) $T_{amb} = 85 \, ^{\circ}C$
- (3) $T_{amb} = 25 \, ^{\circ}C$
- (4) $T_{amb} = -40 \, ^{\circ}C$

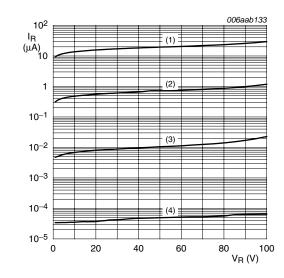
Fig 2. Forward current as a function of forward voltage; typical values



Based on square wave currents.

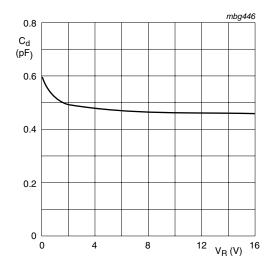
 $T_i = 25$ °C; prior to surge

Fig 3. Non-repetitive peak forward current as a function of pulse duration; maximum values



- (1) $T_{amb} = 150 \, ^{\circ}C$
- (2) $T_{amb} = 85 \, ^{\circ}C$
- (3) $T_{amb} = 25 \, ^{\circ}C$
- (4) $T_{amb} = -40 \, ^{\circ}C$

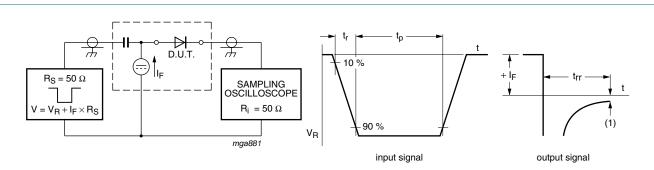
Fig 4. Reverse current as a function of reverse voltage; typical values



f = 1 MHz; T_{amb} = 25 °C

Fig 5. Diode capacitance as a function of reverse voltage; typical values

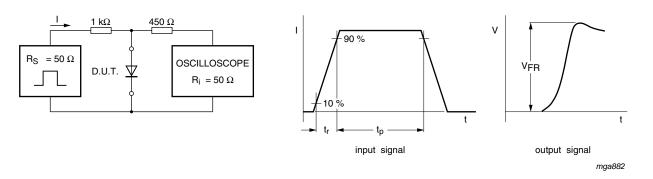
8. Test information



(1) $I_R = 1 \text{ mA}$

Input signal: reverse pulse rise time t_r = 0.6 ns; reverse voltage pulse duration t_p = 100 ns; duty cycle δ = 0.05 Oscilloscope: rise time t_r = 0.35 ns

Fig 6. Reverse recovery time test circuit and waveforms

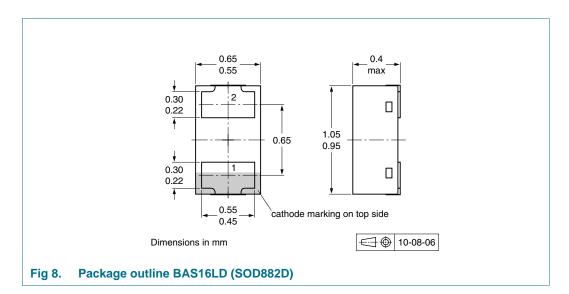


Input signal: forward pulse rise time t_r = 20 ns; forward current pulse duration $t_p \ge 100$ ns; duty cycle $\delta \le 0.005$

Fig 7. Forward recovery voltage test circuit and waveforms

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9. Package outline



10. Packing information

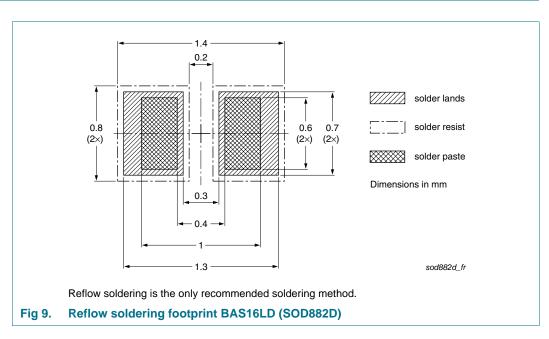
Table 8. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing quantity	
			10000	
BAS16LD	SOD882D	2 mm pitch, 8 mm tape and reel	-315	

^[1] For further information and the availability of packing methods, see Section 14.

11. Soldering



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12. Revision history

Table 9. **Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes
BAS16LD v.1	20101012	Product data sheet	-	-

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13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions"
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